



1435 N. Hayden Road
Scottsdale, AZ 85257-3773

T 480 423 2998
F 480 970 6355

September 5, 2000

*By certified mail
Return receipt requested*

www.axontc.com

Mr. Mark Durcan
Micron Technology, Inc.
8000 S. Federal Way, MS 840
Boise, Idaho 83716-9632

RE: Invention Disclosures (ASU Case Nos)

M1-006	“Solid Solution for the Programmable Metallization Cell”
M1-007	“Optimized Electrodes for the Programmable Metallization Cell”
M1-008	“Programmable Metallization Cell With Floating Electrode”
M1-009	Method for the Synthesis of Macrohomogeneous Germanium Chalcogenide Glasses”
M1-010	“Common Electrode Configurations for the Programmable Metallization Cell”
M1-011	“Ultra Low Energy Programmable Metallization Cell Devices”

Dear Mark,

I have received notification from ASU of the above-referenced invention disclosures. In the opinion of ASU, all the disclosures represent “IMPROVEMENT INVENTIONS” as defined in the Research Agreement between Axon and ASU. I have therefore instructed our patent counsel to prepare, file, prosecute and maintain patents on these disclosures.

This letter is written in compliance of with Paragraph 3.2 of the Research and License Agreement dated March 22, 2000 between Micron Technology, Inc. and Axon Technologies Corporation. The text of each of the referenced disclosures is included with this letter.

Sincerely,

A handwritten signature in black ink, appearing to read 'Vic Lyn'.

Vic Lyn
Executive Vice President

Cc: Roderic Lewis, General Counsel, Micron Technology, Inc.
Michael Kozicki, ASU
Quinn Williams, Snell & Wilmer
Cindy Pillote, Snell & Wilmer

Enclosures